











LP5018, LP5024

ZHCSHV7B - OCTOBER 2018-REVISED OCTOBER 2018

## LP50xx 18/24 通道 12 位 PWM 超低静态电流 I2C RGB LED 驱动器

### 1 特性

- 工作电压范围:
  - V<sub>CC</sub> 范围: 2.7V 至 5.5V
  - 与
    - 1.8V、3.3V 和 5V 电源轨兼容的 EN、SDA 和 SCL 引脚
  - 最大输出电压: 6V
- 24 路高精度恒定电流阱
  - 在整个 V<sub>CC</sub> 范围内,每个通道的最大电流为 25.5mA
  - 当 V<sub>CC</sub> ≥ 3.3V 时,每个通道的最大电流为 35mA
  - 器件间的误差为 ±7%; 通道间的误差为 ±7%
- 超低静态电流:
  - 关断模式: 1µA(最大值), EN处于低电平
  - 省电模式: 10μA(典型), EN 处于高电平, 所有 LED 关断时间大于 30ms
- 每个通道具有一个集成式 12 位 29kHz PWM 发生器:
  - 每个通道具有一个独立的色彩混合寄存器
  - 每个 RGB LED 模块具有一个独立的亮度控制 寄存器
  - 可选的对数或线性标度亮度控制
  - 集成式三相 PWM 相移方案
- 3个可编程组(R、G、B),可轻松对每种颜色进 行软件控制
- 2 个外部硬件地址引脚允许连接多达 4 个器件
- 广播从地址允许同时配置多个器件
- 自动递增允许在一次传输期间写入或读取多个连续的寄存器
- 高达 400kHz 的快速模式 I<sup>2</sup>C 速度

#### 2 应用

用于以下设备的 LED 照明、指示灯和闪烁光:

- 智能扬声器(带语音助理)
- 智能家用电器
- 可视门铃
- 电子智能锁
- 烟雾和热量探测器
- STB 和 DVR
- 智能路由器
- 手持设备

#### 3 说明

在智能家居以及配备人机交互功能的其他 应用中, 高性能 RGB LED 驱动器必不可少。LED 动画效果(如闪烁、呼吸以及追逐)可极大地改善用户体验,同时最大限度地降低系统噪声也至关重要。

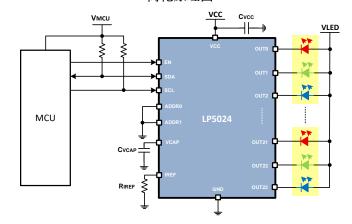
LP50xx 器件是一款 18 或 24 通道恒定电流阱 LED 驱 动器。LP50xx 器件包含集成色彩混合和亮度控制,预配置特性简化了软件编码过程。为每个通道配备的集成式 12 位、29kHz PWM 发生器可实现流畅、清晰的 LED 色彩,并消除了可闻噪声。

#### 器件信息<sup>(1)</sup>

器件型号	封装	封装尺寸 (标称值)		
LP5018	\/OFN (22)	4.00000 4.00000		
LP5024	VQFN (32)	4.00mm × 4.00mm		

(1) 如需了解所有可用封装,请参阅数据表末尾的可订购产品附录。

### 简化原理图





13 机械、封装和可订购信息......45

#### 目录 Programming ...... 18 2 Register Maps ......22 3 Application and Implementation ...... 38 4 修订历史记录 ...... 2 5 Pin Configuration and Functions ...... 4 10 Power Supply Recommendations ...... 41 Specifications...... 6 11 Layout...... 41 Absolute Maximum Ratings ...... 6 11.1 Layout Guidelines ...... 41 11.2 Layout Examples...... 42 Recommended Operating Conditions ...... 6 7.3 12 器件和文档支持 ...... 44 Thermal Information ...... 6 7.4 相关链接.......44 接收文档更新通知 .......44 12.3 社区资源.......44 商标.......44 Detailed Description ...... 11 静电放电警告.......44 Overview ...... 11 Functional Block Diagram ...... 11

## 4 修订历史记录

8.2

注: 之前版本的页码可能与当前版本有所不同。

8.3 Feature Description...... 11

Changes from Revision A (October 2018) to Revision B	Page
Added % after 100 in Parameter for I <sub>ERR_DD</sub> and I <sub>ERR_CC</sub> under OUTPUT STAGE	7
• 已更改 value of "K <sub>IREF</sub> = 100" to "K <sub>IREF</sub> = 105"	
Changes from Original (October 2018) to Revision A	Page
<ul><li>首次发布生产数据数据表</li></ul>	1



### 5 说明 (续)

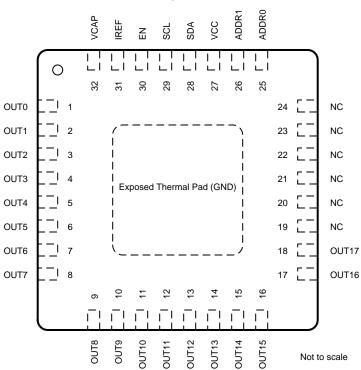
LP50xx 以 12 位 PWM 分辨率和 29kHz 开关频率控制每个 LED 输出,这有助于实现平滑的调光效果和消除可闻噪声。独立的色彩混合和亮度控制寄存器使软件编码变得非常简单。在以淡入淡出类型的呼吸效果为目标时,全局R、G、B 组控制可显著减轻微控制器负载。LP50xx 还可以实现 PWM 相移功能,以帮助在多个 LED 同时打开时降低输入功率预算。

LP50xx 可实现自动节能模式,以实现超低静态电流。当所有通道都关断 30ms 时,该器件的总功耗会降至 10μA,这使得 LP50xx 器件成为电池供电终端设备的潜在选择。

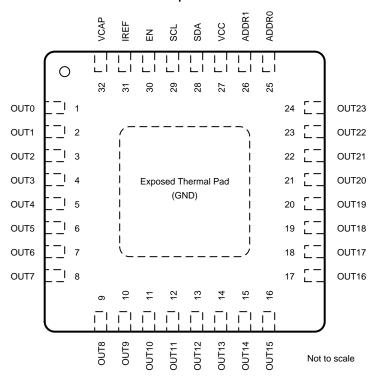


## 6 Pin Configuration and Functions

LP5018 RSM Package 32-Pin VQFN With Exposed Thermal Pad Top View



#### LP5024 RSM Package 32-Pin VQFN With Exposed Thermal Pad Top View





## **Pin Functions**

PIN						
	NO	NO.		DESCRIPTION		
NAME	LP5018	LP5024				
ADDR0	25	25	_	I <sup>2</sup> C slave-address selection pin. This pin must not be left floating.		
ADDR1	26	26	_	I <sup>2</sup> C slave-address selection pin. This pin must not be left floating.		
EN	30	30	I	Chip enable input pin		
IREF	31	31	_	Output current-reference global-setting pin		
NC	19, 20, 21, 22, 23, 24	_	_	No internal connection		
OUT0	1	1	0	Current sink output 0. If not used, this pin can be left floating.		
OUT1	2	2	0	Current sink output 1. If not used, this pin can be left floating.		
OUT2	3	3	0	Current sink output 2. If not used, this pin can be left floating.		
OUT3	4	4	0	Current sink output 3. If not used, this pin can be left floating.		
OUT4	5	5	0	Current sink output 4. If not used, this pin can be left floating.		
OUT5	6	6	0	Current sink output 5. If not used, this pin can be left floating.		
OUT6	7	7	0	Current sink output 6. If not used, this pin can be left floating.		
OUT7	8	8	0	Current sink output 7. If not used, this pin can be left floating.		
OUT8	9	9	0	Current sink output 8. If not used, this pin can be left floating.		
OUT9	10	10	0	Current sink output 9. If not used, this pin can be left floating.		
OUT10	11	11	0	Current sink output 10. If not used, this pin can be left floating.		
OUT11	12	12	0	Current sink output 11. If not used, this pin can be left floating.		
OUT12	13	13	0	Current sink output 12. If not used, this pin can be left floating.		
OUT13	14	14	0	Current sink output 13. If not used, this pin can be left floating.		
OUT14	15	15	0	Current sink output 14. If not used, this pin can be left floating.		
OUT15	16	16	0	Current sink output 15. If not used, this pin can be left floating.		
OUT16	17	17	0	Current sink output 16. If not used, this pin can be left floating.		
OUT17	18	18	0	Current sink output 17. If not used, this pin can be left floating.		
OUT18	_	19	0	Current sink output 18. If not used, this pin can be left floating.		
OUT19	_	20	0	Current sink output 19. If not used, this pin can be left floating.		
OUT20	_	21	0	Current sink output 20. If not used, this pin can be left floating.		
OUT21	_	22	0	Current sink output 21. If not used, this pin can be left floating.		
OUT22	_	23	0	Current sink output 22. If not used, this pin can be left floating.		
OUT23	_	24	0	Current sink output 23. If not used, this pin can be left floating.		
SCL	29	29	I	I <sup>2</sup> C bus clock line. If not used, this pin must be connected to GND or VCC.		
SDA	28	28	I/O	I <sup>2</sup> C bus data line. If not used, this pin must be connected to GND or VCC.		
VCAP	32	32	_	Internal LDO output pin, this pin must be connected to a 1-µF capacitor to GND. Place the capacitor as close to the device as possible.		
VCC	27	27	I	Input power.		
GND	GND		_	Exposed thermal pad also serves the ground pin for the device.		



## 7 Specifications

#### 7.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted)<sup>(1)</sup>

	MIN	MAX	UNIT
Voltage on EN, IREF, OUTx, SCL, SDA, VCC	-0.3	6	V
Voltage on ADDRx	-0.3	VCC+0.3	V
Voltage on VCAP	-0.3	2	V
Continuous power dissipation	Inter	nally limited	
Junction temperature, T <sub>J-MAX</sub>	-40	125	°C
Storage temperature, T <sub>stg</sub>	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 7.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±4000	
$V_{(ESD)}$	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1500	V

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as ±1500
V may actually have higher performance.

## 7.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Input voltage on VCC	2.7	5.5	V
Voltage on OUTx	0	5.5	V
Voltage on ADDRx, EN, SDA, SCL	0	5.5	V
Operating ambient temperature, T <sub>A</sub>	-40	85	°C

#### 7.4 Thermal Information

		LP5018 or LP5024	
	THERMAL METRIC <sup>(1)</sup>	RSM (QFN)	UNIT
		32 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	36.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	34.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	15.9	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	16	°C/W
R <sub>0</sub> JC(bot)	Junction-to-case (bottom) thermal resistance	6.3	°C/W

(1) For more information about traditional and new thermal metrics, see Semiconductor and ICPackage Thermal Metrics .

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Pins listed as ±500 V may actually have higher performance.



### 7.5 Electrical Characteristics

over operating ambient temperature range (-40°C < T<sub>A</sub><85°C) (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER S	UPPLIES (VCC)					
V <sub>VCC</sub>	Supply voltage		2.7		5.5	V
	Shutdown supply current	V <sub>EN</sub> = 0 V		0.2	1	^
	Standby supply current	V <sub>EN</sub> = 3.3 V, Chip_EN = 0 (bit)		6	10	μA
I <sub>VCC</sub>	Normal-mode supply current	With 10-mA LED current per OUTx		5	8	mA
·VCC	Power-save mode supply current	$V_{EN} = 3.3 \text{ V}, \text{Chip\_EN} = 1 \text{ (bit)},$ $Power\_Save\_EN = 1 \text{ (bit)}, \text{ all the}$ $LEDs \text{ off duration} > t_{PSM}$		6	10	μΑ
V <sub>UVR</sub>	Undervoltage restart	V <sub>VCC</sub> rising			2.5	V
V <sub>UVF</sub>	Undervoltage shutdown	V <sub>VCC</sub> falling	2			V
V <sub>UV_HYS</sub>	Undervoltage shutdown hysteresis			0.2		V
OUTPUT S	STAGE (OUTx)					
	Maximum sink current (OUT0-OUTx) (For LP5024, x = 23. For LP5018, x = 17.)	V <sub>VCC</sub> in full range, Max_Current_Option = 0 (bit), PWM = 100%			25.5	mΛ
I <sub>MAX</sub>	Maximum sink current (OUT0-OUTx) (For LP5024, x = 23. For LP5018, x = 17.)	V <sub>VCC</sub> ≥ 3.3 V, Max_Current_Option = 1 (bit), PWM = 100%			35	mA
l	Internal sink current limit (OUT0-OUTx) (For LP5024, $x = 23$ . For LP5018, $x = 17$ .)	V <sub>VCC</sub> in full range, Max_Current_Option = 0 (bit), V <sub>IREF</sub> = 0 V	35	55	80	mA
I <sub>LIM</sub>	Internal sink current limit (OUT0-OUTx) (For LP5024, $x = 23$ . For LP5018, $x = 17$ .)	$V_{VCC} \ge 3.3V$ , Max_Current_Option=1 (bit), $V_{IREF} = 0 V$	40	75	120	
I <sub>lkg</sub>	Leakage current (OUT0-OUTx) (For LP5024, x = 23. For LP5018, x = 17.)	PWM = 0%		0.1	1	μΑ
I <sub>ERR_DD</sub>	Device to device current error, I <sub>ERR_DD</sub> =(I <sub>AVE</sub> -I <sub>SET</sub> )/I <sub>SET</sub> ×100%	All channels' current set to 10 mA. PWM = 100%. Already includes the V <sub>IREF</sub> and K <sub>IREF</sub> tolerance	-7%		7%	
I <sub>ERR_CC</sub>	Channel to channel current error, I <sub>ERR_CC</sub> =(I <sub>OUTX</sub> -I <sub>AVE</sub> )/I <sub>AVE</sub> ×100%	All channels' current set to 10 mA.  PWM = 100%. Already includes the  V <sub>IREF</sub> and K <sub>IREF</sub> tolerance	-7%		7%	
V <sub>IREF</sub>	IREF voltage			0.7		V
K <sub>IREF</sub>	IREF ratio			105		
$f_{PWM}$	PWM switching frequency		21	29		kHz
$V_{SAT}$	Output saturation voltage	V <sub>VCC</sub> in full range, Max_Current_Option = 0 (bit), output current set to 20 mA, the voltage when the LED current has dropped 5%		0.25	0.35	V
OA1		V <sub>VCC</sub> ≥ 3.3 V, Max_Current_Option = 1 (bit), output current set to 20 mA, the voltage when the LED current has dropped 5%		0.3	0.4	
LOGIC INI	PUTS (EN, SCL, SDA, ADDRx)					
V <sub>IL</sub>	Low level input voltage				0.4	V
V <sub>IH</sub>	High level input voltage		1.4			V
I <sub>LOGIC</sub>	Input current		-1		1	μΑ
V <sub>SDA</sub>	SDA output low level	I <sub>PULLUP</sub> = 5 mA			0.4	V
PROTECT	ION CIRCUITS					
T <sub>(TSD)</sub>	Thermal-shutdown junction temperature			160		°C



## **Electrical Characteristics (continued)**

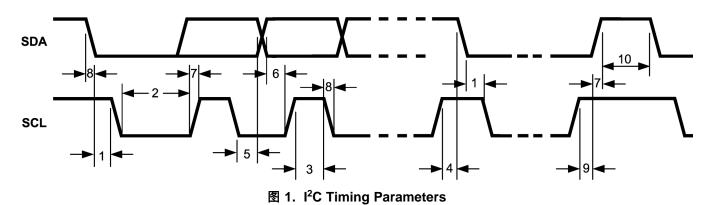
over operating ambient temperature range (-40°C <  $T_A$ <85°C) (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
T <sub>(HYS)</sub>	Thermal shutdown temperature hysteresis			15		°C

## 7.6 Timing Requirements

over operating ambient temperature range (- $40^{\circ}$ C <  $T_A$ < $85^{\circ}$ C) (unless otherwise noted)

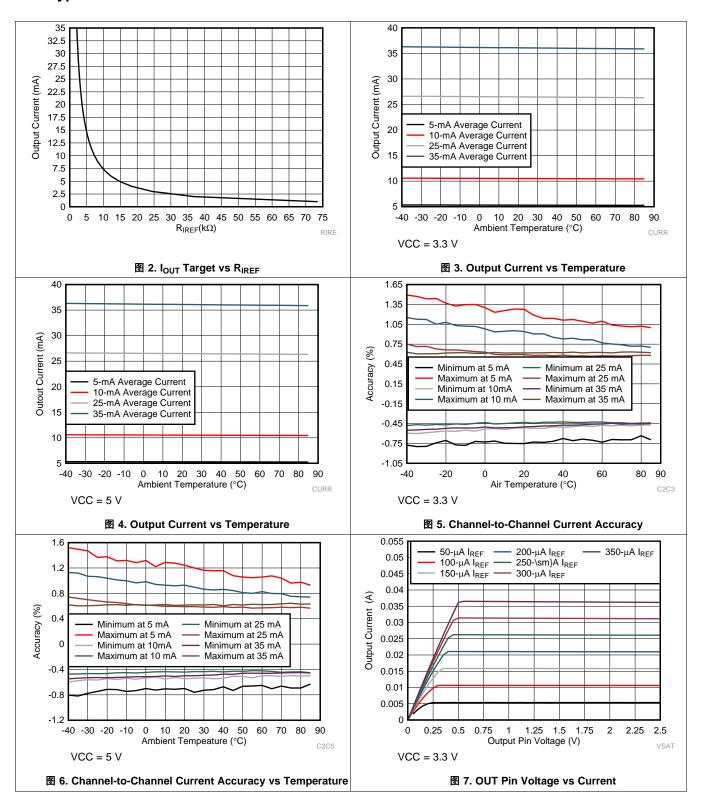
	PARAMETER	MIN	TYP	MAX	UNIT
$f_{OSC}$	Internal oscillator frequency		15		MHz
t <sub>PSM</sub>	Power save mode deglitch time	20	30	40	ms
t <sub>EN_H</sub>	EN first rising edge until first I <sup>2</sup> C access			500	μs
t <sub>EN_L</sub>	EN first falling edge until first I <sup>2</sup> C reset			3	μs
f <sub>SCL</sub>	I <sup>2</sup> C clock frequency			400	kHz
1	Hold time (repeated) START condition	0.6			μs
2	Clock low time	1.3			μs
3	Clock high time	600			ns
4	Setup time for a repeated START condition	600			ns
5	Data hold time	0			ns
6	Data setup time	100			ns
7	Rise time of SDA and SCL	20 + 0.1 C <sub>b</sub>		300	ns
8	Fall time of SDA and SCL	15 + 0.1 C <sub>b</sub>		300	ns
9	Setup time for STOP condition	600			ns
10	Bus free time between a STOP and a START condition	1.3			μs
C <sub>b</sub>	Capacitive load parameter for each bus line Load of 1 pF corresponds to one nanosecond.	10		200	pF



8

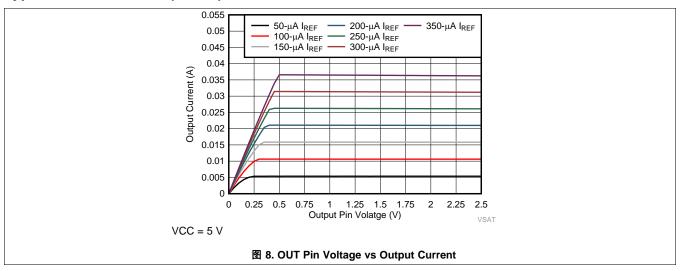


## 7.7 Typical Characteristics





## Typical Characteristics (接下页)





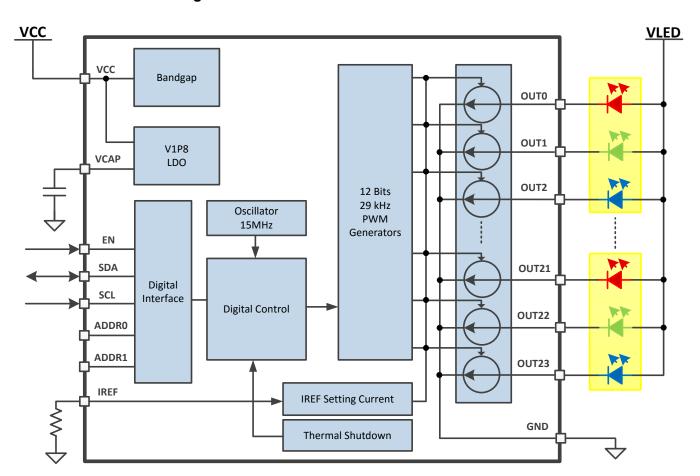
## 8 Detailed Description

#### 8.1 Overview

The LP50xx device is an 18- or 24-channel constant-current-sink LED driver. The LP50xx device includes all necessary power rails, an on-chip oscillator, and a two-wire serial  $I^2C$  interface. The maximum constant-current value of all channels is set by a single external resistor. Two hardware address pins allow up to four devices on the same bus. An automatic power-saving mode is implemented to keep the total current consumption under 10  $\mu$ A, which makes the LP50xx device a potential choice for battery-powered end-equipment.

The LP50xx device is optimized for RGB LEDs regarding to both live effects and software efforts. The LP50xx device controls each LED output with 12-bit PWM resolution at 29-kHz switching frequency, which helps achieve a smooth dimming effect and eliminates audible noise. The independent color-mixing and intensity-control registers make the software coding straightforward. When targeting a fade-in, fade-out type breathing effect, the global RGB bank control reduces the microcontroller loading significantly. The LP50xx device also implements a PWM phase-shifting function to help reduce the input power budget when LEDs turn on simultaneously.

#### 8.2 Functional Block Diagram



#### 8.3 Feature Description

#### 8.3.1 PWM Control for Each Channel

Most traditional LED drivers are designed for the single-color LEDs, in which the high-resolution PWM generator is used for intensity control only. However, for RGB LEDs, both the color mixing and intensity control should be addressed to achieve the target effect. With the traditional solution, the users must handle the color mixing and intensity control simultaneously with a single PWM register. Several undesired effects occur: the limited dimming steps, the complex software design, and the color distortion when using a logarithmic scale control.



The LP50xx device is designed with independent color mixing and intensity control, which makes the RGB LED effects fancy and the control experience straightforward. With the inputs of the color-mixing register and the intensity-control register, the final PWM generator output for each channel is 12-bit resolution and 29-kHz dimming frequency, which helps achieve a smooth dimming effect and eliminates audible noise. See  $\[mathbb{g}\]$  9.

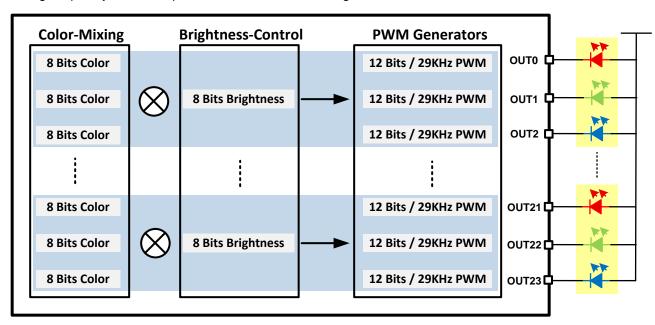


图 9. PWM Control Scheme for Each Channel

#### 8.3.1.1 Independent Color Mixing Per RGB LED Module

Each output channel has its own individual 8-bit color-setting register (OUTx\_COLOR). The device allows every RGB LED module to achieve >16 million ( $256 \times 256 \times 256$ ) color-mixing.

#### 8.3.1.2 Independent Intensity Control Per RGB LED Module

When color is fixed, the independent intensity-control is used to achieve accurate and flexible dimming control for every RGB LED module.

#### 8.3.1.2.1 Intensity-Control Register Configuration

Every three consecutive output channels are assigned to their respective intensity-control register (LEDx\_BRIGHTNESS). For example, OUT0, OUT1, and OUT2 are assigned to LED0\_BRIGHTNESS, so it is recommended to connect the RGB LEDs in the sequence as shown in 表 1. The LP50xx device allows 256-step intensity control for each RGB LED module, which helps achieve a smooth dimming effect.

Keeping FFh (default value) in the LED0\_BRIGHTNESS register results in 100% dimming duty cycle. With this setting, users can just configure the color mixing register by channel to achieve the target dimming effect in a single-color LED application.

#### 8.3.1.2.2 Logarithmic- or Linear-Scale Intensity Control

For human-eye-friendly visual performance, a logarithmic-scale dimming curve is usually implemented in LED drivers. However, for RGB LEDs, if using a single register to achieve both color mixing and intensity control, color distortion can be observed easily when using a logarithmic scale. The LP50xx device, with independent color-mixing and intensity-control registers, implements the logarithmic scale dimming control inside the intensity control function, which solves the color distortion issue effectively. See 10. Also, the LP50xx device allows users to configure the dimming scale either logarithmically or linearly through the global Log\_Scale\_EN register. If a special dimming curve is desired, using the linear scale with software correction is the most flexible approach. See 11.



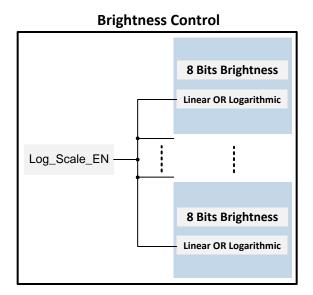


图 10. Logarithmic- or Linear-Scale Intensity Control

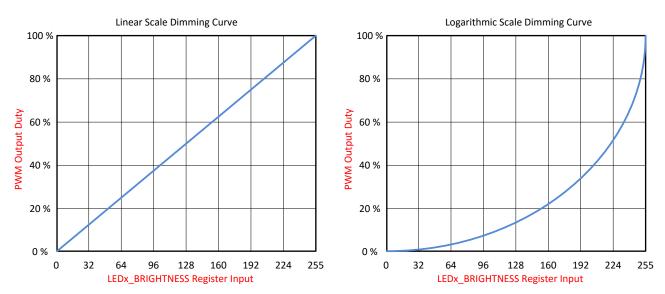


图 11. Logarithmic vs Linear Dimming Curve

#### 8.3.1.3 12-Bit, 29-kHz PWM Generator Per Channel

#### 8.3.1.3.1 PWM Generator

With the inputs of the color mixing and the intensity control, the final output PWM duty cycle is defined as the product obtained by multiplying the color-mixing register value by the related intensity-control register value. The final output PWM duty cycle has 12 bits of control accuracy, which is achieved by a 9 bits of pure PWM resolution and 3 bits of digital dithering control. For 3-bit dithering, every eighth pulse is made 1 LSB longer to increase the average value by 1 / 8th. The LP50xx device allows users to enable or disable the dithering function through the PWM\_Dithering\_EN register. When enabled (default), the output PWM duty-cycle accuracy is 12 bits. When disabled, the output PWM duty-cycle accuracy is 9 bits.

To eliminate the audible noise due to the PWM switching, the LP50xx device sets the PWM switching frequency at 29-kHz, above the 20-kHz human hearing range.



#### 8.3.1.4 PWM Phase-Shifting

A PWM phase-shifting scheme allows delaying the time when each LED driver is active. When the LED drivers are not activated simultaneously, the peak load current from the pre-stage power supply is significantly decreased. The scheme also reduces input-current ripple and ceramic-capacitor audible ringing. LED drivers are grouped into three different phases.

- Phase 1—the rising edge of the PWM pulse is fixed. The falling edge of the pulse is changed when the duty cycle changes. Phase 1 is applied to LED0, LED3, ..., LED21.
- Phase 2—the middle point of the PWM pulse is fixed. The pulse spreads in both directions when the PWM duty cycle is increased. Phase 2 is applied to LED1, LED4, ..., LED22.
- Phase 3—the falling edge of the PWM pulse is fixed. The rising edge of the pulse is changed when the duty cycle changes. Phase 3 is applied to LED2, LED5, ..., LED23.

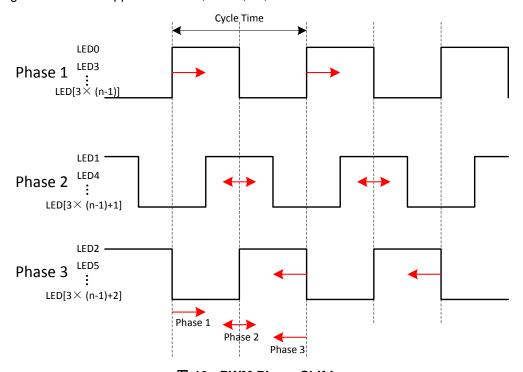


图 12. PWM Phase-Shifting

#### 8.3.2 LED Bank Control

For most LED-animation effects, like blinking and breathing, all the RGB LEDs have the same lighting pattern. Instead of controlling the individual LED separately, which occupies the microcontroller resources heavily, the LP50xx device provides an easy coding approach, the LED bank control.

Each channel can be configured as either independent control or bank control through the LEDx\_Bank\_EN register. When LEDx\_Bank\_EN = 0 (default), the LED is controlled independently by the related color-mixing and intensity-control registers. When LEDx\_Bank\_EN = 1, the LP50xx device drives the LEDs in LED bank-control mode. The LED bank has its own independent PWM control scheme, which is the same structure as the PWM scheme of each channel. See PWM Control for Each Channel for more details. When a channel is configured in LED bank-control mode, the related color mixing and intensity control is governed by the bank control registers (BANK\_A\_COLOR, BANK\_B\_COLOR, BANK\_C\_COLOR, and BANK\_BRIGHTNESS) regardless of the inputs on its own color-mixing and intensity-control registers.



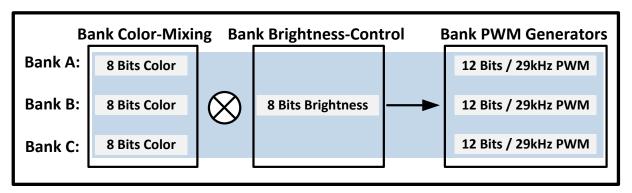


图 13. Bank PWM Control Scheme

## 表 1. Bank Number and LED Number Assignment

OUT NUMBER	BANK Number	RGB LED MODULE NUMBER
OUT0	Bank A	
OUT1	Bank B	LED0
OUT2	Bank C	
OUT3	Bank A	
OUT4	Bank B	LED1
OUT5	Bank C	
OUT6	Bank A	
OUT7	Bank B	LED2
OUT8	Bank C	
OUT9	Bank A	
OUT10	Bank B	LED3
OUT11	Bank C	
OUT12	Bank A	
OUT13	Bank B	LED4
OUT14	Bank C	
OUT15	Bank A	
OUT16	Bank B	LED5
OUT17	Bank C	
OUT18 (LP5024 only)	Bank A	
OUT19 (LP5024 only)	Bank B	LED6
OUT20 (LP5024 only)	Bank C	
OUT21 (LP5024 only)	Bank A	
OUT22 (LP5024 only)	Bank B	LED7
OUT23 (LP5024 only)	Bank C	



With the bank control configuration, the LP50xx device enables users to achieve smooth and live LED effects globally with an ultrasimple software effort. 图 14 shows an example using LED0 as an independent RGB indicator and others with group breathing effect.

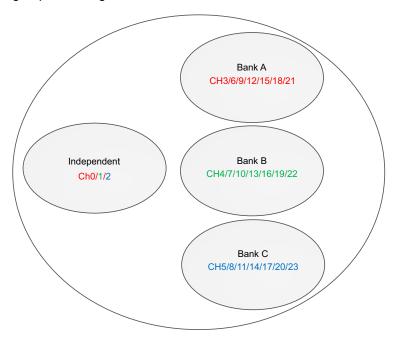


图 14. Bank PWM Control Example

#### 8.3.3 Current Range Setting

The constant-current value ( $I_{SET}$ ) of all 24 channels is set by a single external resistor,  $R_{IREF}$ . The value of  $R_{IREF}$  can be calculated by 公式 1.

$$R_{IREF} = K_{IREF} \times \frac{V_{IREF}}{I_{SFT}}$$

where:

• 
$$K_{IREF} = 105$$
  
•  $V_{IREF} = 0.7 \text{ V}$  (1)

With the IREF pin floating, the output current is close to zero. With the IREF pin shorted to GND, the LP50xx device provides internal current-limit protection, and the output-channel maximum current is limited to  $I_{LIM}$ .

The LP50xx device supports two levels of maximum output current, I<sub>MAX</sub>.

- When V<sub>CC</sub> is in the range from 2.7 V to 5.5 V, and the Max\_Current\_Option (bit) = 0, I<sub>MAX</sub> = 25.5 mA.
- When V<sub>CC</sub> is in the range from 3.3 V to 5.5 V, and the Max\_Current\_Option (bit) = 1, I<sub>MAX</sub> = 35 mA.

#### 8.3.4 Automatic Power-Save Mode

When all the LED outputs are inactive, the LP50xx device is able to enter power-save mode automatically, thus lowering idle-current consumption down to 10  $\mu$ A (typical). Automatic power-save mode is enabled when register bit Power\_Save\_EN = 1 (default) and all the LEDs are off for a duration of >30 ms. Almost all analog blocks are powered down in power-save mode. If any I<sup>2</sup>C command to the device occurs, the LP50xx device returns to NORMAL mode.



#### 8.3.5 Protection Features

#### 8.3.5.1 Thermal Shutdown

The LP50xx device implements a thermal shutdown mechanism to protect the device from damage due to overheating. When the junction temperature rises to 160°C (typical), the device switches into shutdown mode. The LP50xx device releases thermal shutdown when the junction temperature of the device is reduced to 145°C (typical).

#### 8.3.5.2 UVLO

The LP50xx device has an internal comparator that monitors the voltage at  $V_{CC}$ . When  $V_{CC}$  is below  $V_{UVF}$ , reset is active and the LP50xx device is in the INITIALIZATION state.

#### 8.4 Device Functional Modes

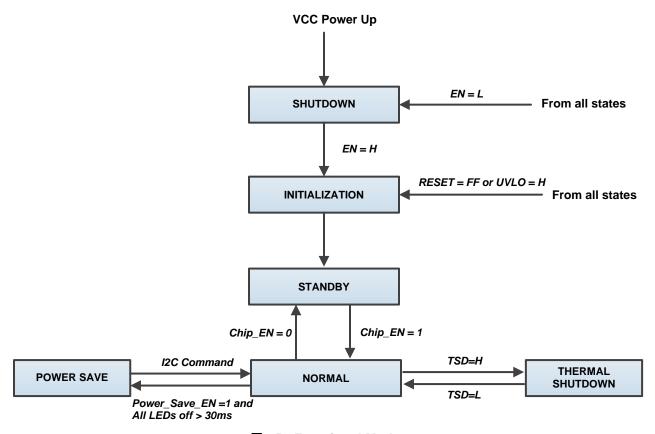


图 15. Functional Modes

- INITIALIZATION: The device enters into INITIALIZATION mode when EN = H. In this mode, all the registers
  are reset. Entry can also be from any state, if the RESET (register) = FFh or UVLO is active.
- NORMAL: The device enters the NORMAL mode when Chip\_EN (register) = 1. I<sub>CC</sub> is 10 mA (typ.).
- POWER SAVE: The device automatically enters the POWER SAVE mode when Power\_Save\_EN (register) =
   1 and all the LEDs are off for a duration of >30 ms. In POWER SAVE mode, analog blocks are disabled to
   minimize power consumption, but the registers retain the data and keep it available via I<sup>2</sup>C. I<sub>CC</sub> is 10 μA (typ.).
   In case of any I<sup>2</sup>C command to this device, it returns to the NORMAL mode.
- **SHUTDOWN**: The device enters into SHUTDOWN mode from all states on  $V_{CC}$  power up or when EN = L.  $I_{CC}$  is < 1  $\mu$ A (max).
- **STANDBY**: The device enters the STANDBY mode when Chip\_EN (register) = 0. In this mode, all the OUTx pins are shut down, but the registers retain the data and keep it available via I<sup>2</sup>C. STANDBY is the low-power-consumption mode, when all circuit functions are disabled. I<sub>CC</sub> is 10 μA (typ.).
- THERMAL SHUTDOWN: The device automatically enters the THERMAL SHUTDOWN mode when the



## Device Functional Modes (接下页)

junction temperature exceeds 160°C (typical). In this mode, all the OUTx outputs are shut down. If the junction temperature decreases below 145°C (typical), the device returns to the NORMAL mode.

### 8.5 Programming

#### 8.5.1 I<sup>2</sup>C Interface

The I<sup>2</sup>C-compatible two-wire serial interface provides access to the programmable functions and registers on the device. This protocol uses a two-wire interface for bidirectional communications between the devices connected to the bus. The two interface lines are the serial data line (SDA) and the serial clock line (SCL). Every device on the bus is assigned a unique address and acts as either a master or a slave depending on whether it generates or receives the serial clock, SCL. The SCL and SDA lines should each have a pullup resistor placed somewhere on the line and remain HIGH even when the bus is idle.

#### 8.5.1.1 Data Validity

The data on SDA line must be stable during the HIGH period of the clock signal (SCL). In other words, the state of the data line can only be changed when the clock signal is LOW.

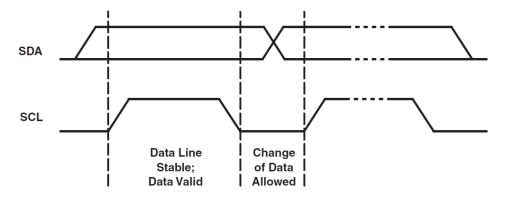


图 16. Data Validity

#### 8.5.1.2 Start and Stop Conditions

START and STOP conditions classify the beginning and the end of the data transfer session. A START condition is defined as the SDA signal transitioning from HIGH to LOW while the SCL line is HIGH. A STOP condition is defined as the SDA transitioning from LOW to HIGH while SCL is HIGH. The bus master always generates START and STOP conditions. The bus is considered to be busy after a START condition and free after a STOP condition. During data transmission, the bus master can generate repeated START conditions. First START and repeated START conditions are functionally equivalent.

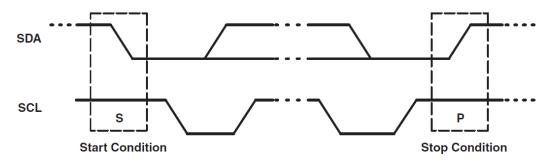


图 17. Start and Stop Conditions



## Programming (接下页)

#### 8.5.1.3 Transferring Data

Every byte put on the SDA line must be eight bits long, with the most-significant bit (MSB) being transferred first. Each byte of data must be followed by an acknowledge bit. The acknowledge-related clock pulse is generated by the master. The master releases the SDA line (HIGH) during the acknowledge clock pulse. The device pulls down the SDA line during the ninth clock pulse, signifying an acknowledge. The device generates an acknowledge after each byte has been received.

There is one exception to the acknowledge-after-every-byte rule. When the master is the receiver, it must indicate to the transmitter an end of data by not acknowledging (negative acknowledge) the last byte clocked out of the slave. This negative acknowledge still includes the acknowledge clock pulse (generated by the master), but the SDA line is not pulled down.

After the START condition, the bus master sends a chip address. This address is seven bits long followed by an eighth bit which is a data direction bit (READ or WRITE). For the eighth bit, a 0 indicates a WRITE, and a 1 indicates a READ. The second byte selects the register to which the data is written. The third byte contains data to write to the selected register.

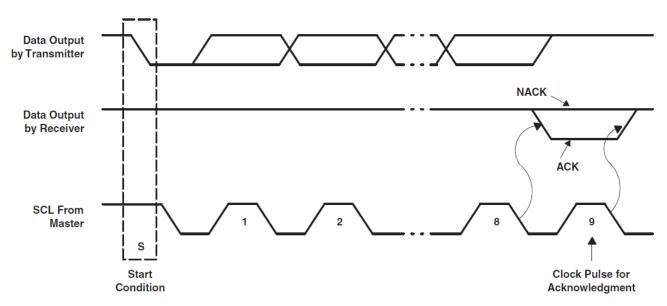


图 18. Acknowledge and Not Acknowledge on I<sup>2</sup>C Bus

#### 8.5.1.4 PC Slave Addressing

The device slave address is defined by connecting GND or VCC to the ADDR0 and ADDR1 pins. A total of four independent slave addresses can be realized by combinations when GND or VCC is connected to the ADDR0 and ADDR1 pins (see 表 2 and 表 3).

The device responds to a broadcast slave address regardless of the setting of the ADDR0 and ADDR1 pins. Global writes to the broadcast address can be used for configuring all devices simultaneously. The device supports global read using a broadcast address; however, the data read is only valid if all devices on the I<sup>2</sup>C bus contain the same value in the addressed register.

表 2.	Slave-	Address	Com	binations
------	--------	---------	-----	-----------

ADDR1	ADDDO	SLAVE ADDRESS			
ADDRI	ADDR0	INDEPENDENT	BROADCAST		
GND	GND	010 1000			
GND	VCC	010 1001	044 4400		
VCC	GND	010 1010	011 1100		
VCC	VCC	010 1011			



#### 表 3. Chip Address

	SLAVE ADDRESS							
	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Independent	0	1	0	1	0	ADDR1	ADDR0	1 or 0
Broadcast	0	1	1	1	1	0	0	1 or 0

#### 8.5.1.5 Control-Register Write Cycle

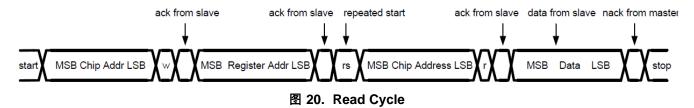
- The master device generates a start condition.
- The master device sends the slave address (7 bits) and the data direction bit ( $R/\overline{W} = 0$ ).
- The slave device sends an acknowledge signal if the slave address is correct.
- The master device sends the control register address (8 bits).
- · The slave device sends an acknowledge signal.
- The master device sends the data byte to be written to the addressed register.
- The slave device sends an acknowledge signal.
- If the master device sends further data bytes, the control register address of the slave is incremented by 1 after the acknowledge signal. To reduce program load time, the device supports address auto incrementation. The register address is incremented after each 8 data bits.
- The write cycle ends when the master device creates a stop condition.



图 19. Write Cycle

#### 8.5.1.6 Control-Register Read Cycle

- The master device generates a start condition.
- The master device sends the slave address (7 bits) and the data direction bit ( $R/\overline{W} = 0$ ).
- The slave device sends an acknowledge signal if the slave address is correct.
- The master device sends the control register address (8 bits).
- The slave device sends an acknowledge signal.
- The master device generates a repeated-start condition.
- The master device sends the slave address (7 bits) and the data direction bit ( $R/\overline{W} = 1$ ).
- The slave device sends an acknowledge signal if the slave address is correct.
- The slave device sends the data byte from the addressed register.
- If the master device sends an acknowledge signal, the control-register address is incremented by 1. The slave device sends the data byte from the addressed register. To reduce program load time, the device supports address auto incrementation. The register address is incremented after each 8 data bits.
- The read cycle ends when the master device does not generate an acknowledge signal after a data byte and generates a stop condition.





#### 8.5.1.7 Auto-Increment Feature

The auto-increment feature allows writing or reading several consecutive registers within one transmission. For example, when an 8-bit word is sent to the device, the internal address index counter is incremented by 1, and the next register is written. The auto-increment feature is enabled by default and can be disabled by setting the Auto\_Incr\_EN bit = 0 in the DEVICE\_CONFIG1 register. The auto-increment feature is applied for the full register address from 0h to FFh.



## 8.6 Register Maps

表 4 lists the memory-mapped registers of the device.

## 表 4. Register Maps

REGISTER	ADDR	TYPE	D7	D6	D5	D4	D3	D2	D1	D0	DEF-
DEVICE_	00h	R/W	RESERVED	Chip_EN			RESE	RVED			AULT 00h
CONFIG0  DEVICE_ CONFIG1	01h	R/W	RESE	<u> </u>	Log_Scale_EN	Power_Save_ EN	Auto_Incr_EN	PWM_ Dithering_EN	Max_Current_ Option	LED_Global Off	3Ch
LED_CONFIG0	02h	R/W	LED7_Bank_EN (Only for LP5024)	LED6_Bank_EN (Only for LP5024)	LED5_Bank_EN	LED4_Bank_EN	LED3_Bank_EN		·	LED0_Bank_EN	00h
BANK_ BRIGHTNESS	03h	R/W				Bank_B	rightness				FFh
BANK_A_ COLOR	04h	R/W				Bank_/	A_Color				00h
BANK_B_ COLOR	05h	R/W				Bank_l	3_Color				00h
BANK_C_ COLOR	06h	R/W		Bank_C_Color							
LED0_ BRIGHTNESS	07h	R/W		LED0_Brightness							
LED1_ BRIGHTNESS	08h	R/W		LED1_Brightness							FFh
LED2_ BRIGHTNESS	09h	R/W				LED2_B	rightness				FFh
LED3_ BRIGHTNESS	0Ah	R/W				LED3_B	rightness				FFh
LED4_ BRIGHTNESS	0Bh	R/W				LED4_B	rightness				FFh
LED5_ BRIGHTNESS	0Ch	R/W				LED5_B	rightness				FFh
LED6_ BRIGHTNESS	0Dh	R/W					rightness LP5024)				FFh
LED7_ BRIGHTNESS	0Eh	R/W					rightness LP5024)				FFh
OUT0_COLOR	0Fh	R/W				OUT0	_Color				00h
OUT1_COLOR	10h	R/W				OUT1	_Color				00h
OUT2_COLOR	11h	R/W									00h
OUT3_COLOR	12h	R/W				OUT3	_Color				00h

版权 © 2018, Texas Instruments Incorporated

www.ti.com.cn



# Register Maps (接下页)

## 表 4. Register Maps (接下页)

REGISTER NAME	ADDR	TYPE	D7	D6	D5	D4	D3	D2	D1	D0	DEF- AULT	
OUT4_COLOR	13h	R/W		OUT4_Color								
OUT5_COLOR	14h	R/W		OUT5_Color								
OUT6_COLOR	15h	R/W				OUT	_Color				00h	
OUT7_COLOR	16h	R/W				OUT7	_Color				00h	
OUT8_COLOR	17h	R/W				OUT	_Color				00h	
OUT9_COLOR	18h	R/W				OUTS	_Color				00h	
OUT10_COLOR	19h	R/W				OUT1	O_Color				00h	
OUT11_COLOR	1Ah	R/W				OUT1	1_Color				00h	
OUT12_COLOR	1Bh	$R/\overline{W}$				OUT1:	2_Color				00h	
OUT13_COLOR	1Ch	$R/\overline{W}$				OUT1:	3_Color				00h	
OUT14_COLOR	1Dh	$R/\overline{W}$		OUT14_Color								
OUT15_COLOR	1Eh	R/W		OUT15_Color								
OUT16_COLOR	1Fh	R/W		OUT16_Color								
OUT17_COLOR	20h	$R/\overline{W}$				OUT1	7_Color				00h	
OUT18_COLOR	21h	R/W					3_Color · LP5024)				00h	
OUT19_COLOR	22h	R/W					9_Color · LP5024)				00h	
OUT20_COLOR	23h	R/W					O_Color · LP5024)				00h	
OUT21_COLOR	24h	R/W					1_Color · LP5024)				00h	
OUT22_COLOR	25h	R/W		OUT22_Color (Only for LP5024)							00h	
OUT23_COLOR	26h	R/W		OUT23_Color (Only for LP5024)								
RESET	27h	W				Re	eset				00h	

23 版权 © 2018, Texas Instruments Incorporated



## 表 5. Access Type Codes

ACCESS TYPE	CODE	DESCRIPTION						
Read Type								
R	R	Read						
Write Type								
W	W	Write						
Reset or Default	Reset or Default Value							
-n		Value after reset or the default value						

## 8.6.1 DEVICE\_CONFIG0 (Address = 0h) [reset = 0h]

DEVICE\_CONFIG0 is shown in 图 21 and described in 表 6.

Return to 表 4.

## 图 21. DEVICE\_CONFIG0 Register

7	6	5	4	3	2	1	0
RESERVED	Chip_EN			RESE	RVED		
R/W-0h	R/W-0h	R/W-0h					

### 表 6. DEVICE\_CONFIG0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	RESERVED	R/W	0h	Reserved
6	Chip_EN	R/W	0h	1 = LP50xx enabled 0 = LP50xx not enabled
5–0	RESERVED	R/W	0h	Reserved

## 8.6.2 DEVICE\_CONFIG1 (Address = 1h) [reset = 3Ch]

DEVICE\_CONFIG1 is shown in 图 22 and described in 表 7.

Return to 表 4.

### 图 22. DEVICE\_CONFIG1 Register

7	6	5	4	3	2	1	0
RESE	RVED	Log_Scale_EN	Power_Save_E	Auto_Incr_EN		Optional_Headr	LED_Global Off
			N		_EN	oom	
RΛ	∇-0h	R/W-1h	R/W-1h	R/W-1h	R/W-1h	R/W-0h	R/W-0h

### 表 7. DEVICE\_CONFIG1 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–6	RESERVED	R/W	0h	Reserved
5	Log_Scale_EN	R/W	1h	1 = Logarithmic scale dimming curve enabled 0 = Linear scale dimming curve enabled
4	Power_Save_EN	R/W	1h	1 = Automatic power-saving mode enabled 0 = Automatic power-saving mode not enabled
3	Auto_Incr_EN	R/W	1h	1 = Automatic increment mode enabled 0 = Automatic increment mode not enabled
2	PWM_Dithering_EN	R/W	1h	1 = PWM dithering mode enabled 0 = PWM dithering mode not enabled
1	Max_Current_Option	R/W	0h	1 = Output maximum current I <sub>MAX</sub> = 35 mA. 0 = Output maximum current I <sub>MAX</sub> = 25.5 mA.
0	LED_Global Off	R/W	0h	1 = Shut down all LEDs 0 = Normal operation



## 8.6.3 LED\_CONFIG0 (Address = 2h) [reset = 00h]

LED\_CONFIG0 is shown in 图 23 and described in 表 8.

Return to 表 4.

## 图 23. LED\_CONFIG0 Register

7	6	5	4	3	2	1	0
LED7_Bank_E N	LED6_Bank_E N	LED5_Bank_E N	LED4_Bank_E N	LED3_Bank_E N	LED2_Bank_E N	LED1_Bank_E N	LED0_Bank_E N
R/W-0h							

## 表 8. LED\_CONFIG0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	LED7_Bank_EN	R/W	0h	1 = LED7 bank control mode enabled 0 = LED7 independent control mode enabled
6	LED6_Bank_EN	R/W	0h	1 = LED6 bank control mode enabled 0 = LED6 independent control mode enabled
5	LED5_Bank_EN	R/W	0h	1 = LED5 bank control mode enabled 0 = LED5 independent control mode enabled
4	LED4_Bank_EN	R/W	0h	1 = LED4 bank control mode enabled 0 = LED4 independent control mode enabled
3	LED3_Bank_EN	R/W	0h	1 = LED3 bank control mode enabled 0 = LED3 Independent control mode enabled
2	LED2_Bank_EN	R/W	0h	1 = LED2 bank control mode enabled 0 = LED2 independent control mode enabled
1	LED1_Bank_EN	R/W	0h	1 = LED1 bank control mode enabled 0 = LED1 independent control mode enabled
0	LED0_Bank_EN	R/W	0h	1 = LED0 bank control mode enabled 0 = LED0 independent control mode enabled

### 8.6.4 BANK\_BRIGHTNESS (Address = 3h) [reset = FFh]

BANK\_BRIGHTNESS is shown in 图 24 and described in 表 9.

Return to 表 4.

#### 图 24. BANK\_BRIGHTNESS Register



#### 表 9. BANK\_BRIGHTNESS Register Field Descriptions

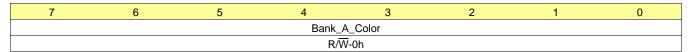
Bit	Field	Туре	Reset	Description
7–0	Bank_Brightness	R/W	FFh	FFh = 100% of full brightness
				 80h = 50% of full brightness
				 00h = 0% of full brightness

### 8.6.5 BANK\_A\_COLOR (Address = 4h) [reset = 00h]

BANK\_A\_COLOR is shown in 图 25 and described in 表 10.



#### 图 25. BANK\_A\_COLOR Register



### 表 10. BANK\_A\_COLOR Register Field Descriptions

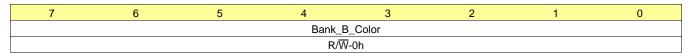
Bit	Field	Туре	Reset	Description
7–0	Bank_A_Color	R/W	0h	FFh = The color mixing percentage is 100%.
				80h = The color mixing percentage is 50%.
				00h = The color mixing percentage is 0%.

### 8.6.6 BANK\_B\_COLOR (Address = 5h) [reset = 00h]

BANK\_B\_COLOR is shown in 图 26 and described in 表 11.

Return to 表 4.

### 图 26. BANK\_B\_COLOR Register



#### 表 11. BANK\_B\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	Bank_B_Color	R/W	0h	FFh = The color mixing percentage is 100%.
				80h = The color mixing percentage is 50%
				00h = The color mixing percentage is 0%.

#### 8.6.7 BANK\_C\_COLOR (Address = 6h) [reset = 00h]

BANK\_C\_COLOR is shown in 图 27 and described in 表 12.

Return to 表 4.

## 图 27. BANK\_C\_COLOR Register

7	6	5	5 4		2	1	0
Bank_C_Color							
			R/W				

### 表 12. BANK\_C\_COLOR Register Field Descriptions

Field	Туре	Reset	Description
Bank_C_Color	R/W	0h	FFh = The color mixing percentage is 100%.
			80h = The color mixing percentage is 50% 00h = The color mixing percentage is 0%.
			ank_C_Color R/W 0h

### 8.6.8 LED0\_BRIGHTNESS (Address = 7h) [reset = FFh]

LED0\_BRIGHTNESS is shown in 图 28 and described in 表 13.



#### 图 28. LED0\_BRIGHTNESS Register

7	6	5	4	3	2	1	0
LED0_Brightness							
			R/W	-FFh			

### 表 13. LED0\_BRIGHTNESS Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	LED0_Brightness	R/W	FFh	FFh = 100% of full intensity
				80h = 50% of full intensity
				 00h = 0% of full intensity

### 8.6.9 LED1\_BRIGHTNESS (Address = 8h) [reset = FFh]

LED1\_BRIGHTNESS is shown in 图 29 and described in 表 14.

Return to 表 4.

### 图 29. LED1\_BRIGHTNESS Register

7	6	5 4		3	2	1	0	
LED1_Brightness								
			R/W	-FFh				

#### 表 14. LED1\_BRIGHTNESS Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	LED1_Brightness	R/W	FFh	FFh = 100% of full intensity
				 80h = 50% of full intensity
				00h = 0% of full intensity

#### 8.6.10 LED2\_BRIGHTNESS (Address = 9h) [reset = FFh]

LED2\_BRIGHTNESS is shown in 图 30 and described in 表 15.

Return to 表 4.

#### 图 30. LED2 BRIGHTNESS Register

7	6	5 4		3	2	1	0
LED2_Brightness							
			R/W				

#### 表 15. LED2\_BRIGHTNESS Register Field Descriptions

Field	Type	Reset	Description
LED2_Brightness	R/W	FFh	FFh = 100% of full intensity
			80h = 50% of full intensity 00h = 0% of full intensity
			ED2_Brightness R/W FFh

### 8.6.11 LED3\_BRIGHTNESS (Address = 0Ah) [reset = FFh]

LED3\_BRIGHTNESS is shown in 图 31 and described in 表 16.



#### 图 31. LED3\_BRIGHTNESS Register

7	6	5 4		3	2	1	0
LED3_Brightness							
			R/W	/-FFh			

### 表 16. LED3\_BRIGHTNESS Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	LED3_Brightness	R/W	FFh	FFh = 100% of full intensity
				 80h = 50% of full intensity
				00h = 0% of full intensity

### 8.6.12 LED4\_BRIGHTNESS (Address = 0Bh) [reset = FFh]

LED4\_BRIGHTNESS is shown in 图 32 and described in 表 17.

Return to 表 4.

### 图 32. LED4\_BRIGHTNESS Register

7	6	5	4	3	2	1	0
			LED4_B	rightness			
			R/W	-FFh			

#### 表 17. LED4\_BRIGHTNESS Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	LED4_Brightness	R/W	FFh	FFh = 100% of full intensity
				 80h = 50% of full intensity
				00h = 0% of full intensity

#### 8.6.13 LED5\_BRIGHTNESS (Address = 0Ch) [reset = FFh]

LED5\_BRIGHTNESS is shown in 图 33 and described in 表 18.

Return to 表 4.

#### 图 33. LED5\_BRIGHTNESS Register

7	6	5	4	3	2	1	0
			LED5_B	rightness			
			R/W	-FFh			

#### 表 18. LED5\_BRIGHTNESS Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	LED5_Brightness	R/W	FFh	FFh = 100% of full intensity
				80h = 50% of full intensity
				00h = 0% of full intensity

### 8.6.14 LED6\_BRIGHTNESS (Address = 0Dh) [reset = FFh]

LED6\_BRIGHTNESS is shown in 图 34 and described in 表 19.



#### 图 34. LED6\_BRIGHTNESS Register

7	6	5	4	3	2	1	0
			LED6_B	rightness			
			R/W	/-FFh			

### 表 19. LED6\_BRIGHTNESS Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	LED6_Brightness	R/W	FFh	FFh = 100% of full intensity
				80h = 50% of full intensity
				 00h = 0% of full intensity

### 8.6.15 LED7\_BRIGHTNESS (Address = 0Eh) [reset = FFh]

LED7\_BRIGHTNESS is shown in 图 35 and described in 表 20.

Return to 表 4.

### 图 35. LED7\_BRIGHTNESS Register

7	6	5	4	3	2	1	0
	LED7_Brightness						
			R/W	-FFh			

#### 表 20. LED7\_BRIGHTNESS Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	LED7_Brightness	R/W	FFh	FFh = 100% of full intensity
				 80h = 50% of full intensity
				00h = 0% of full intensity

#### 8.6.16 OUTO\_COLOR (Address = 0Fh) [reset = 00h]

OUT0\_COLOR is shown in 图 36 and described in 表 21.

Return to 表 4.

## 图 36. OUT0\_COLOR Register

7	6	5	4	3	2	1	0
			OUT0	_Color			
			R/W	/-00h			

### 表 21. OUT0\_COLOR Register Field Descriptions

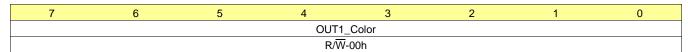
Bit	Field	Туре	Reset	Description
7–0	OUT0_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%
				00h = The color mixing percentage is 100%.

### 8.6.17 OUT1\_COLOR (Address = 10h) [reset = 00h]

OUT1\_COLOR is shown in 图 37 and described in 表 22.



#### 图 37. OUT1\_COLOR Register



### 表 22. OUT1\_COLOR Register Field Descriptions

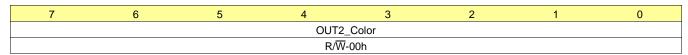
Bit	Field	Туре	Reset	Description
7–0	OUT1_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				 80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.18 OUT2\_COLOR (Address = 11h) [reset = 00h]

OUT2\_COLOR is shown in 图 38 and described in 表 23.

Return to 表 4.

### 图 38. OUT2\_COLOR Register



#### 表 23. OUT2\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT2_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				 80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

#### 8.6.19 OUT3\_COLOR (Address = 12h) [reset = 00h]

OUT3\_COLOR is shown in 图 39 and described in 表 24.

Return to 表 4.

#### 图 39. OUT3 COLOR Register

7	6	5	4	3	2	1	0
			OUT3	_Color			
			R/W	-00h			

### 表 24. OUT3\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT3_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50% 00h = The color mixing percentage is 100%.

## 8.6.20 OUT4\_COLOR (Address = 13h) [reset = 00h]

OUT4\_COLOR is shown in 图 40 and described in 表 25.



#### 图 40. OUT4\_COLOR Register

7	6	5	4	3	2	1	0
			OUT4	_Color			
			R/W	/-00h			

### 表 25. OUT4\_COLOR Register Field Descriptions

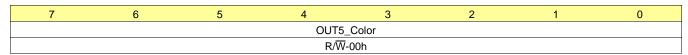
Bit	Field	Туре	Reset	Description
7–0	OUT4_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				 00h = The color mixing percentage is 100%.

### 8.6.21 OUT5\_COLOR (Address = 14h) [reset = 00h]

OUT5\_COLOR is shown in 图 41 and described in 表 26.

Return to 表 4.

### 图 41. OUT5\_COLOR Register



#### 表 26. OUT5\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT5_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				 80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.22 OUT6\_COLOR (Address = 15h) [reset = 00h]

OUT6\_COLOR is shown in 图 42 and described in 表 27.

Return to 表 4.

#### 图 42. OUT6 COLOR Register

7	6	5	4	3	2	1	0
			OUT6	_Color			
			R/W	/-00h			

### 表 27. OUT6\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT6_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.23 OUT7\_COLOR (Address = 16h) [reset = 00h]

OUT7\_COLOR is shown in 图 43 and described in 表 28.



#### 图 43. OUT7\_COLOR Register

7	6	5	4	3	2	1	0
			OUT7	_Color			
			R/W	7-00h			

### 表 28. OUT7\_COLOR Register Field Descriptions

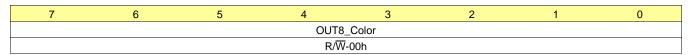
Bit	Field	Туре	Reset	Description
7–0	OUT7_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				 80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.24 OUT8\_COLOR (Address = 17h) [reset = 00h]

OUT8\_COLOR is shown in 图 44 and described in 表 29.

Return to 表 4.

### 图 44. OUT8\_COLOR Register



### 表 29. OUT8\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT8_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.25 OUT9\_COLOR (Address = 18h) [reset = 00h]

OUT9\_COLOR is shown in 图 45 and described in 表 30.

Return to 表 4.

### 图 45. OUT9\_COLOR Register

7	6	5	4	3	2	1	0
			OUT9	_Color			
			R/W	/-00h			

### 表 30. OUT9\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT9_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50% 00h = The color mixing percentage is 100%.

### 8.6.26 OUT10\_COLOR (Address = 19h) [reset = 00h]

OUT10\_COLOR is shown in 图 46 and described in 表 31.



#### 图 46. OUT10\_COLOR Register

7	6	5	4	3	2	1	0
OUT10_Color							
			R/W	7-00h			

### 表 31. OUT10\_COLOR Register Field Descriptions

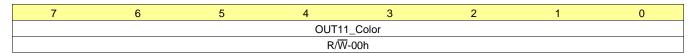
Bit	Field	Туре	Reset	Description
7–0	OUT10_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				 80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.27 **OUT11\_COLOR** (Address = 1Ah) [reset = 00h]

OUT11\_COLOR is shown in 图 47 and described in 表 32.

Return to 表 4.

## 图 47. OUT11\_COLOR Register



#### 表 32. OUT11\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT11_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

#### 8.6.28 **OUT12\_COLOR** (Address = 1Bh) [reset = 00h]

OUT12\_COLOR is shown in 图 48 and described in 表 33.

Return to 表 4.

#### 图 48. OUT12\_COLOR Register

7	6	5	4	3	2	1	0		
	OUT12_Color								
			R/W	7-00h					

### 表 33. OUT12\_COLOR Register Field Descriptions

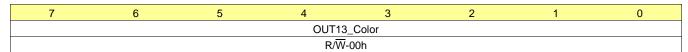
Bit	Field	Туре	Reset	Description
7–0	OUT12_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

## 8.6.29 **OUT13\_COLOR** (Address = 1Ch) [reset = 00h]

OUT13\_COLOR is shown in 图 49 and described in 表 34.



#### 图 49. OUT13\_COLOR Register



### 表 34. OUT13\_COLOR Register Field Descriptions

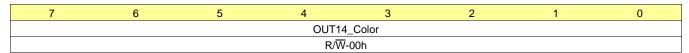
Bit	Field	Туре	Reset	Description
7–0	OUT13_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.30 OUT14\_COLOR (Address = 1Dh) [reset = 00h]

OUT14\_COLOR is shown in 图 50 and described in 表 35.

Return to 表 4.

### 图 50. OUT14\_COLOR Register



#### 表 35. OUT14\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT14_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

#### 8.6.31 **OUT15\_COLOR** (Address = 1Eh) [reset = 00h]

OUT15\_COLOR is shown in 图 51 and described in 表 36.

Return to 表 4.

#### 图 51. OUT15 COLOR Register

7	6	5	4	3	2	1	0			
	OUT15_Color									
			R/W	7-00h						

### 表 36. OUT15\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT15_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.32 **OUT16\_COLOR** (Address = 1Fh) [reset = 00h]

OUT16\_COLOR is shown in 图 52 and described in 表 37.



#### 图 52. OUT16\_COLOR Register

7	6	5	4	3	2	1	0	
OUT16_Color								
			R/W	-00h				

### 表 37. OUT16\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT16_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.33 OUT17\_COLOR (Address = 20h) [reset = 00h]

OUT17\_COLOR is shown in 图 53 and described in 表 38.

Return to 表 4.

### 图 53. OUT17\_COLOR Register

7	6	5	4	3	2	1	0			
	OUT17_Color									
			R/W	7-00h						

#### 表 38. OUT17\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT17_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.34 OUT18\_COLOR (Address = 21h) [reset = 00h]

OUT18\_COLOR is shown in 图 54 and described in 表 39.

Return to 表 4.

### 图 54. OUT18\_COLOR Register

7	6	5	4	3	2	1	0
	OUT18_Color						
R/₩-00h							

### 表 39. OUT18\_COLOR Register Field Descriptions

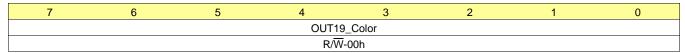
Bit	Field	Туре	Reset	Description
7–0	OUT18_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.35 OUT19\_COLOR (Address = 22h) [reset = 00h]

OUT19\_COLOR is shown in 图 55 and described in 表 40.



#### 图 55. OUT19\_COLOR Register



### 表 40. OUT19\_COLOR Register Field Descriptions

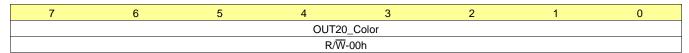
Bit	Field	Туре	Reset	Description
7–0	OUT19_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.36 OUT20\_COLOR (Address = 23h) [reset = 00h]

OUT20\_COLOR is shown in 图 56 and described in 表 41.

Return to 表 4.

### 图 56. OUT20\_COLOR Register



#### 表 41. OUT20\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT20_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				 80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

#### 8.6.37 OUT21\_COLOR (Address = 24h) [reset = 00h]

OUT21\_COLOR is shown in 图 57 and described in 表 42.

Return to 表 4.

#### 图 57. OUT21 COLOR Register

7	6	5	4	3	2	1	0
	OUT21_Color						
R/₩-00h							

### 表 42. OUT21\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT21_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				 80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

### 8.6.38 OUT22\_COLOR (Address = 25h) [reset = 00h]

OUT22\_COLOR is shown in 图 58 and described in 表 43.



## 图 58. OUT22\_COLOR Register

7	6	5	4	3	2	1	0				
	OUT22_Color										
			R/W	-00h							

## 表 43. OUT22\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT22_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				 80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

## 8.6.39 OUT23\_COLOR (Address = 26h) [reset = 00h]

OUT23\_COLOR is shown in 图 59 and described in 表 44.

Return to 表 4.

## 图 59. OUT23\_COLOR Register

7	6	5	4	3	2	1	0			
OUT23_Color										
			R/W	7-00h						

## 表 44. OUT23\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT23_Color	R/W	00h	FFh = The color mixing percentage is 0%.
				80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

## 8.6.40 RESET (Address = 27h) [reset = 00h]

RESET is shown in 图 60 and described in 表 45.

Return to 表 4.

## 图 60. RESET Register

7	6	5	4	3	2	1	0			
Reset										
	W-00h									

## 表 45. OUT14\_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	Reset	W	00h	FFh = Reset all the registers to default value.



## 9 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

## 9.1 Application Information

The LP50xx device is an 18- or 24-channel constant-current-sink LED driver. The LP50xx device improves the user experience in color mixing and intensity control, for both live effects and coding effort. The optimized performance for RGB LEDs makes it a good choice for human-machine interaction applications.

## 9.2 Typical Application

The LP50xx design supports up to four devices in parallel with different configurations on the ADDR0 and ADDR1 pins.



## Typical Application (接下页)

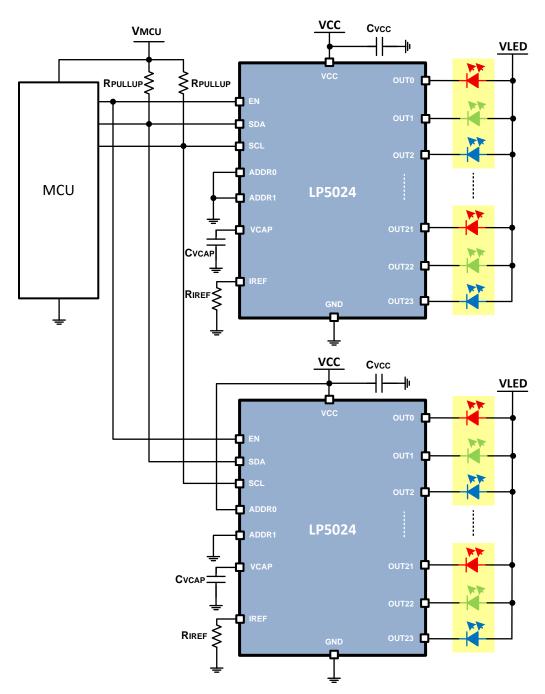


图 61. Driving Dual LP5024 Application Example

## 9.2.1 Design Requirements

Set the LED current to 15 mA using the  $R_{IREF}$  resistor.

## 9.2.2 Detailed Design Procedure

LP50xx scales up the reference current ( $I_{REF}$ ) set by the external resistor ( $R_{IREF}$ ) to sink the output current ( $I_{OUT}$ ) at each output port. The following formula can be used to calculate the external resistor ( $R_{IREF}$ ):



## Typical Application (接下页)

$$R_{IREF} = K_{IREF} \times \frac{V_{IREF}}{I_{SET}}$$
 (2)

The SCL and SDA lines must each have a pullup resistor placed somewhere on the line (the pullup resistors are normally located on the bus master). In typical applications, values of 1.8 k $\Omega$  to 4.7 k $\Omega$  are used.

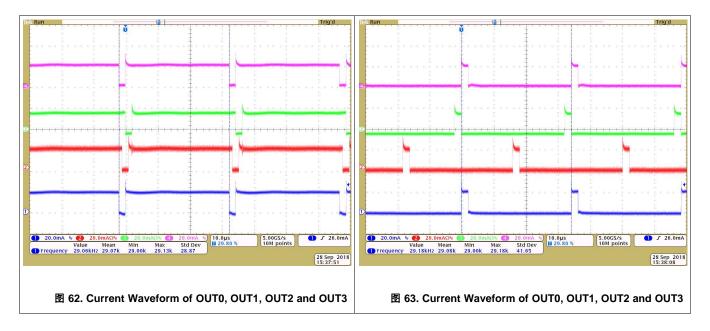
VCAP is internal LDO output pin. This pin must be connected through a 1-μF capacitor to GND. Place the capacitor as close to the device as possible.

TI recommends having a 1-µF capacitor between VCC and GND to ensure proper operation. Place the capacitor as close to the device as possible.

## 9.2.3 Application Curves

The test condition for is that the testing is under bank control, using the following register values: 0x02 (0xFF), 0x04 (0xA0), 0x05 (0xA0), 0x06 (0xA0).

The test condition for is that the testing is under bank control, using the following register values: 0x02 (0xFF), 0x04 (0x10), 0x05 (0x10), 0x06 (0x10).





## 10 Power Supply Recommendations

The device is designed to operate from a  $V_{VCC}$  input-voltage supply range between 2.7 V and 5.5 V. This input supply must be well-regulated and able to withstand maximum input current and maintain stable voltage without voltage drop even in a load-transition condition (start-up or rapid intensity change). The resistance of the input supply rail must be low enough that the input-current transient does not cause a drop below a 2.7-V level in the LP50xx  $V_{VCC}$  supply voltage.

## 11 Layout

## 11.1 Layout Guidelines

To prevent thermal shutdown, the junction temperature,  $T_J$ , must be less than  $T_{(TSD)}$ . If the voltage drop across the output channels is high, the device power dissipation can be large. The LP50xx device has very good thermal performance because of the thermal pad design; however, the PCB layout is also very important to ensure that the device has good thermal performance. Good PCB design can optimize heat transfer, which is essential for the long-term reliability of the device.

Use the following guidelines when designing the device layout:

- Place the C<sub>VCAP</sub>, C<sub>VCC</sub>and R<sub>IREF</sub> as close to the device as possible. Also, TI recommends to put the ground plane as 图 64 and 图 65.
- Maximize the copper coverage on the PCB to increase the thermal conductivity of the board. The major heat flow path from the package to the ambient is through copper on the PCB. Maximum copper density is extremely important when no heat sinks are attached to the PCB on the other side from the package.
- Add as many thermal vias as possible directly under the package ground pad to optimize the thermal conductivity of the board.
- Use either plated-shut or plugged and capped vias for all the thermal vias on both sides of the board to
  prevent solder voids. To ensure reliability and performance, the solder coverage should be at least 85%.



## 11.2 Layout Examples

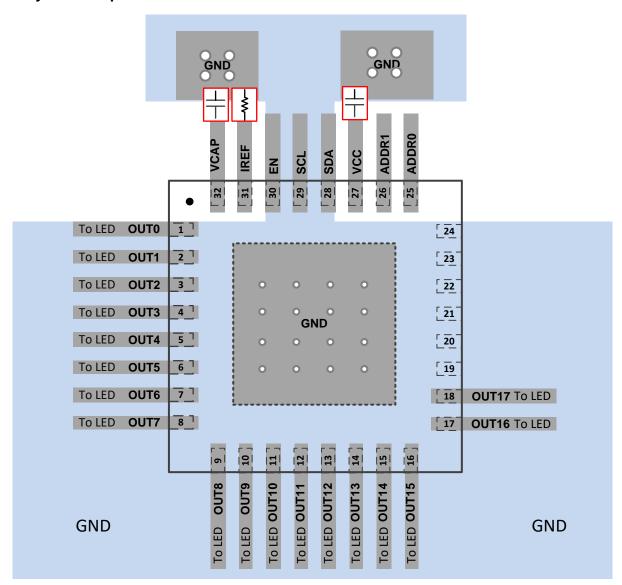


图 64. LP5018 Layout Example



## Layout Examples (接下页)

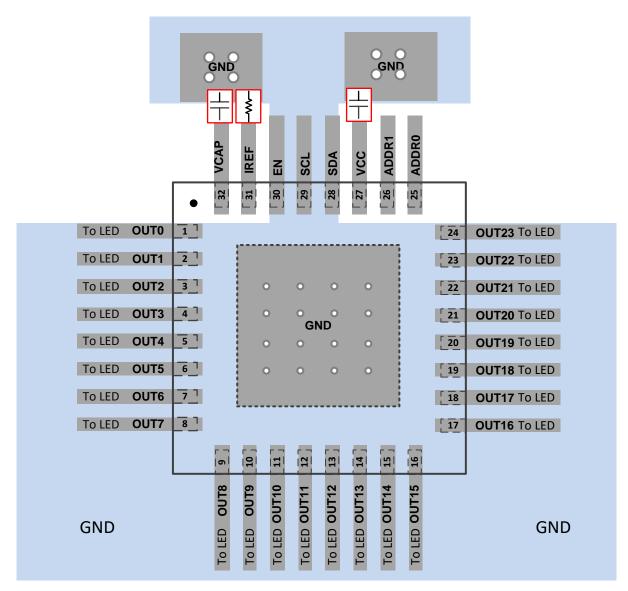


图 65. LP5024 Layout Example



## 12 器件和文档支持

#### 12.1 相关链接

下表列出了快速访问链接。类别包括技术文档、支持和社区资源、工具和软件,以及立即订购快速访问。

#### 表 46. 相关链接

器件	产品文件夹	立即订购	技术文档	工具与软件	支持和社区
LP5018	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
LP5024	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处

## 12.2 接收文档更新通知

要接收文档更新通知,请导航至 Tl.com.cn 上的器件产品文件夹。单击右上角的*通知我*进行注册,即可每周接收产 品信息更改摘要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

## 12.3 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商"按照原样"提供。这些内容并不构成 TI 技术规范, 并且不一定反映 TI 的观点;请参阅 TI 的 《使用条款》。

TI E2E™ 在线社区 TI 的工程师对工程师 (E2E) 社区。此社区的创建目的在于促进工程师之间的协作。在 e2e.ti.com 中,您可以咨询问题、分享知识、拓展思路并与同行工程师一道帮助解决问题。

TI 参考设计支持 可帮助您快速查找有帮助的 E2E 论坛、设计支持工具以及技术支持的联系信息。 设计支持

## 12.4 商标

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

#### 静电放电警告



ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序,可 能会损坏集成电路。



🕼 ESD 的损坏小至导致微小的性能降级,大至整个器件故障。 精密的集成电路可能更容易受到损坏,这是因为非常细微的参数更改都可 能会导致器件与其发布的规格不相符。

#### 12.6 术语表

SLYZ022 — TI 术语表。

这份术语表列出并解释术语、缩写和定义。



# 13 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更,恕不另行通知,且 不会对此文档进行修订。如需获取此数据表的浏览器版本,请查看左侧的导航面板。

## 重要声明和免责声明

TI 均以"原样"提供技术性及可靠性数据(包括数据表)、设计资源(包括参考设计)、应用或其他设计建议、网络工具、安全信息和其他资源,不保证其中不含任何瑕疵,且不做任何明示或暗示的担保,包括但不限于对适销性、适合某特定用途或不侵犯任何第三方知识产权的暗示担保。

所述资源可供专业开发人员应用TI产品进行设计使用。您将对以下行为独自承担全部责任: (1)针对您的应用选择合适的TI产品; (2)设计、验证并测试您的应用; (3)确保您的应用满足相应标准以及任何其他安全、安保或其他要求。所述资源如有变更,恕不另行通知。TI对您使用所述资源的授权仅限于开发资源所涉及TI产品的相关应用。除此之外不得复制或展示所述资源,也不提供其它TI或任何第三方的知识产权授权许可。如因使用所述资源而产生任何索赔、赔偿、成本、损失及债务等,TI对此概不负责,并且您须赔偿由此对TI及其代表造成的损害。

TI 所提供产品均受TI 的销售条款 (http://www.ti.com.cn/zh-cn/legal/termsofsale.html) 以及ti.com.cn上或随附TI产品提供的其他可适用条款的约束。TI提供所述资源并不扩展或以其他方式更改TI 针对TI 产品所发布的可适用的担保范围或担保免责声明。

邮寄地址: 上海市浦东新区世纪大道 1568 号中建大厦 32 楼,邮政编码: 200122 Copyright © 2018 德州仪器半导体技术(上海)有限公司



## PACKAGE OPTION ADDENDUM

24-Oct-2018

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LP5018RSMR	ACTIVE	VQFN	RSM	32	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LP 5018	Samples
LP5024RSMR	ACTIVE	VQFN	RSM	32	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LP 5024	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





24-Oct-2018

## PACKAGE MATERIALS INFORMATION

www.ti.com 12-Mar-2019

## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP5018RSMR	VQFN	RSM	32	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2
LP5024RSMR	VQFN	RSM	32	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2

www.ti.com 12-Mar-2019



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP5018RSMR	VQFN	RSM	32	3000	367.0	367.0	35.0
LP5024RSMR	VQFN	RSM	32	3000	367.0	367.0	35.0



- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. QFN (Quad Flatpack No-Lead) Package configuration.
  - The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.



## RSM (S-PVQFN-N32)

PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4207868-2/1 07/14

NOTE: All linear dimensions are in millimeters



# RSM (S-PVQFN-N32)

## PLASTIC QUAD FLATPACK NO-LEAD



#### NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.



## 重要声明和免责声明

TI 均以"原样"提供技术性及可靠性数据(包括数据表)、设计资源(包括参考设计)、应用或其他设计建议、网络工具、安全信息和其他资源,不保证其中不含任何瑕疵,且不做任何明示或暗示的担保,包括但不限于对适销性、适合某特定用途或不侵犯任何第三方知识产权的暗示担保。

所述资源可供专业开发人员应用TI产品进行设计使用。您将对以下行为独自承担全部责任: (1)针对您的应用选择合适的TI产品; (2)设计、验证并测试您的应用; (3)确保您的应用满足相应标准以及任何其他安全、安保或其他要求。所述资源如有变更,恕不另行通知。TI对您使用所述资源的授权仅限于开发资源所涉及TI产品的相关应用。除此之外不得复制或展示所述资源,也不提供其它TI或任何第三方的知识产权授权许可。如因使用所述资源而产生任何索赔、赔偿、成本、损失及债务等,TI对此概不负责,并且您须赔偿由此对TI及其代表造成的损害。

TI 所提供产品均受TI 的销售条款 (http://www.ti.com.cn/zh-cn/legal/termsofsale.html) 以及ti.com.cn上或随附TI产品提供的其他可适用条款的约束。TI提供所述资源并不扩展或以其他方式更改TI 针对TI 产品所发布的可适用的担保范围或担保免责声明。

邮寄地址: 上海市浦东新区世纪大道 1568 号中建大厦 32 楼,邮政编码: 200122 Copyright © 2019 德州仪器半导体技术(上海)有限公司